











TPS73801-SEP

ZHCSJ39 - DECEMBER 2018

采用增强型航天塑料的 TPS73801-SEP 1A 低噪声快速瞬态响应低压降稳压器

1 特性

- VID V62/18616
- 耐辐射
 - 单粒子锁定 (SEL) 在 125°C 下的抗扰度可达 43MeV-cm²/mg
 - 每个晶圆批次的 RLAT 总电离剂量 (TID) 高达 20krad(Si)
- 增强型航天塑料
 - 受控基线
 - 金线
 - NiPdAu 铅涂层
 - 同一组装和测试场所
 - 同一制造场所
 - 支持军用(-55°C 至 125°C)温度范围
 - 延长的产品生命周期
 - 延长的产品变更通知
 - 产品可追溯性
 - 采用增强型模具化合物实现低释气
- 针对快速瞬态响应进行了优化
- 输出电流: 1A
- 压降电压: 300mV
- 低噪声: 45μV_{RMS} (10Hz 至 100kHz)
- 1mA 静态电流
- 无需保护二极管
- 压降中的受控静态电流
- 可调节输出电压: 1.21V 至 20V
- 关断模式下静态电流小于 1µA
- 与 10µF 输出电容器一起工作时保持稳定
- 与陶瓷电容器一起工作时保持稳定
- 电池反向保护
- 无反向电流
- 热限制

2 应用

- 支持近地轨道空间 应用
- 用于射频、VCO、接收器和放大器的耐辐射低噪声 线性稳压器
- 洁净模拟电源要求
- 航天卫星有效载荷

3 说明

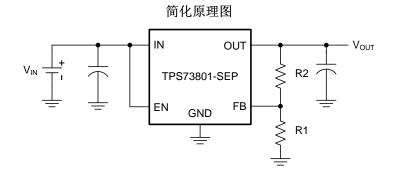
TPS73801-SEP 是一款针对快速瞬态响应进行了优化的低压降 (LDO) 稳压器。该器件能够支持 1A 的输出电流(压降为 300mV)。工作静态电流为 1mA,在关断时下降至小于 1µA。静态电流受到很好的控制;与许多其他稳压器一样,它在压降时不上升。除了快速瞬态响应,TPS73801 稳压器还具有极低的输出噪声,这使得它非常适合灵敏射频电源 应用。

输出电压范围为 1.21 至 20V。TPS73801-SEP 稳压器可在与低至 10μF 的输出电容器一起工作时保持稳定。与其它稳压器一同使用时的常见情况一样,在无需额外等效串联电阻 (ESR) 的前提下可使用小型陶瓷电容器。内部保护电路包括反向电池保护、电流限制、热限制和反向电流保护。此器件可被用作一个基准电压为1.21V的可调器件。TPS73801-SEP 稳压器采用 6 引脚 TO-223 (DCQ) 封装。

器件信息(1)

器件型号	等级	封装
TPS73801MDCQTPSEP	20krad(Ci) DLAT	COT 222 (6)
TPS73801MDCQPSEP	20krad(Si) RLAT	SOT-223 (6)

(1) 如需了解所有可用封装,请参阅数据表末尾的可订购产品附录。







目录

1	特性1	7.	4 Device Functional Modes	12
2	· · · · · · · · · · · · · · · · · · ·	8 Ar	oplication and Implementation	13
3			1 Application Information	
4	修订历史记录		2 Typical Application	
5	Pin Configuration and Functions	9 Pc	ower Supply Recommendations	15
6	Specifications4	10 La	ayout	15
•	6.1 Absolute Maximum Ratings 4	10	0.1 Layout Guidelines	15
	6.2 ESD Ratings	10	0.2 Layout Example	16
	6.3 Recommended Operating Conditions	10	0.3 Thermal Considerations	16
	6.4 Thermal Information	11 器	件和文档支持	18
	6.5 Electrical Characteristics 5	11	.1 接收文档更新通知	18
	6.6 Typical Characteristics 6	11	.2 社区资源	18
7	Detailed Description 10	11	.3 商标	18
-	7.1 Overview	11	.4 静电放电警告	18
	7.2 Functional Block Diagram		.5 术语表	
	7.3 Feature Description	12 机	械、封装和可订购信息	19

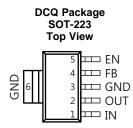
4 修订历史记录

注: 之前版本的页码可能与当前版本有所不同。

日期	修订版本	说明
2018 年 12 月	*	初始发行版。



5 Pin Configuration and Functions



Pin Functions

	PIN	1/0	DESCRIPTION					
NO.	NAME	1/0	DESCRIPTION					
1	IN	_	Input. Power is supplied to the device through the IN pin. A bypass capacitor is required on this pin if the device is more than six inches away from the main input filter capacitor. In general, the output impedance of a battery rises with frequency, so it is advisable to include a bypass capacitor in battery-powered circuits. A bypass capacitor (ceramic) in the range of 1 μ F to 10 μ F is sufficient. The TPS73801-SEP regulators are designed to withstand reverse voltages on the IN pin with respect to ground and the OUT pin. In the case of a reverse input, which can happen if a battery is plugged in backwards, the device acts as if there is a diode in series with its input. There is no reverse current flow into the regulator, and no reverse voltage appears at the load. The device protects both itself and the load.					
2	OUT	_	Output. The output supplies power to the load. A minimum output capacitor (ceramic) of 10 µF is required to prevent oscillations. Larger output capacitors are required for applications with large transient loads to limit peak voltage transients.					
3	GND	_	Ground.					
4	FB	I	Feedback. This is the input to the error amplifier. This pin is internally clamped to ± 7 V. It has a bias current of 3 μ A that flows into the pin. The FB pin voltage is 1.21 V referenced to ground, and the output voltage range is 1.21 V to 20 V.					
5	EN	I	Enable. The EN pin is used to put the TPS73801-SEP regulators into a low-power shutdown state. The output is off when the EN pin is pulled low. The EN pin can be driven either by 5-V logic or open-collector gate, normally several microamperes, and the EN pin current, typically 3 μ A. If unused, the EN pin must be connected to the IN pin. The device is in the low-power shutdown state if the EN pin is not connected.					
6	GND	_	Ground.					

TEXAS INSTRUMENTS

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{IN}		IN	-20	20	
	Input voltage	OUT	-20	20	
		Input-to-output differential (2)	-20	20	V
		FB	-7	7	
		EN	-20	20	
t _{short}	Output short-circuit duration		Indefinite		
TJ	Operating virtual-junction tem	- 55	150	°C	
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
\/	Flootroototic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾		\/
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_{IN}	Input voltage	V _{OUT} + VDO	20	V
V_{IH}	EN high-level input voltage	2	20	V
V_{IL}	EN low-level input voltage		0.25	V
T_{J}	Recommended operating junction temperature	– 55	125	°C

6.4 Thermal Information

		TPS73801-SEP	
	THERMAL METRIC ⁽¹⁾	DCQ (SOT-223)	UNIT
		6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	50.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	31.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	5.1	°C/W
ΨЈТ	Junction-to-top characterization parameter	1	°C/W
ΨЈВ	Junction-to-board characterization parameter	5	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	_	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

⁽²⁾ Absolute maximum input-to-output differential voltage cannot be achieved with all combinations of rated IN pin and OUT pin voltages. With the IN pin at 20 V, the OUT pin may not be pulled below 0 V. The total measured voltage from IN to OUT cannot exceed ±20 V.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.5 Electrical Characteristics

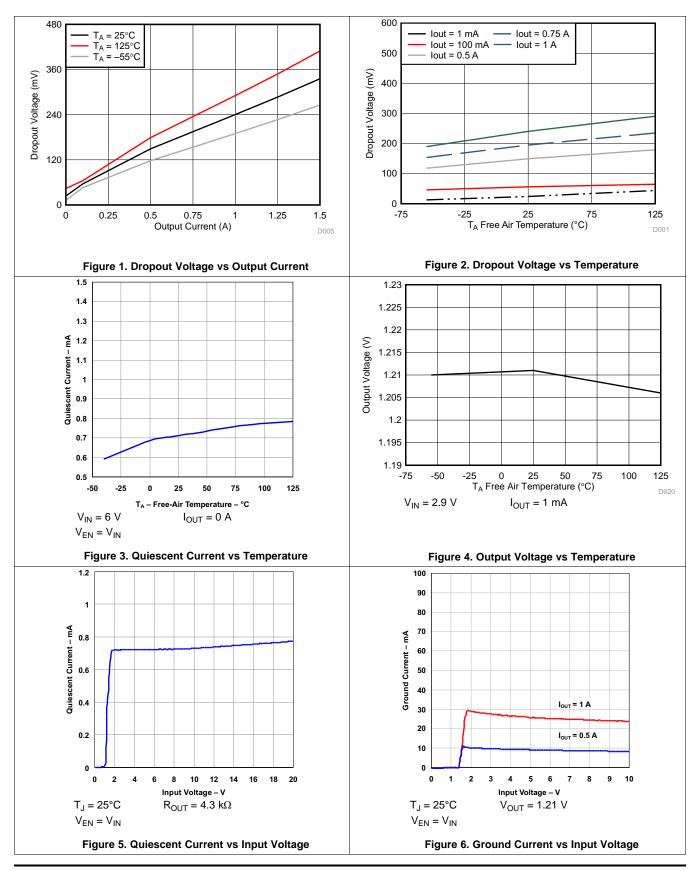
Over operating temperature range T_A = -55°C to 125°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	T _J	MIN	TYP ⁽¹⁾	MAX	UNIT	
V _{IN}	Input voltage (2)(3)		25°C	2.2	1.9	20	V	
		V _{IN} = 2.21 V, I _{LOAD} = 1 mA	25°C	1.192	1.21	1.228		
V_{FB}	FB pin voltage (2)(4)	V_{IN} = 2.5 V to 20 V, I_{LOAD} = 1 mA to 1 A	Full range	1.174	1.21	1.246	V	
	Line regulation ⁽²⁾	ΔV_{IN} = 2.21 V to 20 V, I_{LOAD} = 1 mA	Full range		1.5	5	mV	
	Load regulation ⁽²⁾	V _{IN} = 2.5 V,	25°C		2	8	mV	
	Load regulation.	$\Delta I_{LOAD} = 1$ mA to 1 A	Full range			18	IIIV	
		l -1 mΛ	25°C		0.02	0.06		
		I _{LOAD} = 1 mA	Full range			0.10		
		1 100 1	25°C		0.1	0.17		
V_{DO}	Dropout voltage (3)(5)(6)	I _{LOAD} = 100 mA	Full range			0.22	V	
	$V_{IN} = V_{OUT(NOMINAL)}$	I 500 A	25°C		0.19	0.27	V	
		$I_{LOAD} = 500 \text{ mA}$	Full range			0.35		
			25°C		0.24	0.30		
		$I_{LOAD} = 1 A$	Full range			0.40		
	GND pin current ^{(6) (7)} V _{IN} = V _{OUT(NOMINAL)} + 1	I _{LOAD} = 0 mA	Full range		1	1.5		
		I _{LOAD} = 1 mA	Full range		1.1	1.6		
I_{GND}					3.8	5.5	mA	
					15	25		
		I _{LOAD} = 1 A	Full range		35	80		
V _N	Output voltage noise	C _{OUT} = 10 μF, I _{LOAD} = 1 A, B _W = 10 Hz to 100 kHz	25°C		45		μV_{RMS}	
I _{FB}	FB pin bias current ⁽²⁾⁽⁸⁾		25°C		3	10	μΑ	
V	Churt day on the sach and	V _{OUT} = OFF to ON	Full range		0.9	2		
V_{EN}	Shutdown threshold	V _{OUT} = ON to OFF	Full range	0.15	0.75		V	
	=	V _{EN} = 0 V	25°C		0.01	1		
I _{EN}	EN pin current	V _{EN} = 20 V	25°C		3	30	μA	
	Quiescent current in shutdown	V _{IN} = 6 V, V _{EN} = 0 V 25°C			0.01	1	μA	
PSRR	Ripple rejection ⁽⁹⁾	$V_{\text{IN}} - V_{\text{OUT}} = 1.5 \text{ V (avg)}, V_{\text{RIPPLE}} = 0.5 \text{ V}_{\text{P-P}}, $ 25°C 55 63					dB	
	Current limit	V _{IN} = 7 V, V _{OUT} = 0 V	25°C		2		^	
I _{CL}	Current IIIIII	V _{IN} = V _{OUT(NOMINAL)} + 1	Full range	1.6			Α	
I _{REV}	Input reverse leakage current	$V_{IN} = -20 \text{ V}, V_{OUT} = 0 \text{ V}$	Full range			1	mA	
I _{RO}	Reverse output current ⁽¹⁰⁾	V _{OUT} = 1.21 V, V _{IN} < 1.21 V	25°C		300	600	μA	

- Typical values represent the likely parametric nominal values determined at the time of characterization. Typical values depend on the application and configuration and may vary over time. Typical values are not ensured on production material.
- The TPS73801-SEP is tested and specified for these conditions with the FB pin connected to the OUT pin.
- Dropout voltages are limited by the minimum input voltage specification under some output voltage/load conditions.
- Operating conditions are limited by maximum junction temperature. The regulated output voltage specification does not apply for all possible combinations of input voltage and output current. When operating at maximum input voltage, the output current range must be limited. When operating at maximum output current, the input voltage range must be limited.
- Dropout voltage is the minimum input to output voltage differential needed to maintain regulation at a specified output current. In dropout, the output voltage is equal to: $V_{IN} - V_{DROPOUT}$. To satisfy requirements for minimum input voltage, the TPS73801-SEP is tested and specified for these conditions with an external
- resistor divider (two 4.12-kΩ resistors) for an output voltage of 2.4 V. The external resistor divider adds a 300-mA DC load on the output.
- GND pin current is tested with V_{IN} = (V_{OUT(NOMINAL)} + 1 V) and a current source load. The GND pin current decreases at higher input voltages.
- FB pin bias current flows into the FB pin.
- Parameter is specified by characterization and is not tested in production.
- (10) Reverse output current is tested with the IN pin grounded and the OUT pin forced to the rated output voltage. This current flows into the OUT pin and out the GND pin.

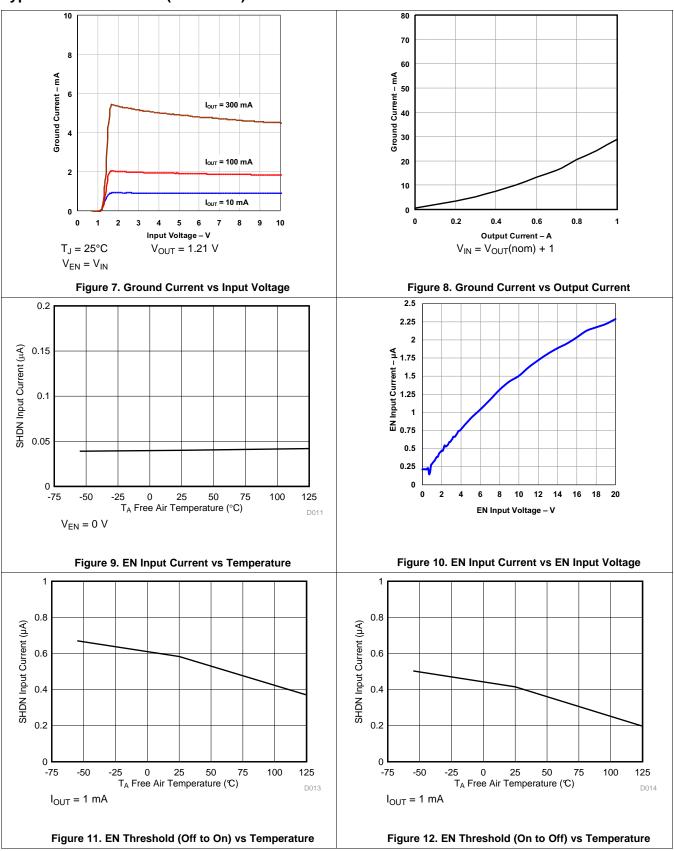
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6.6 Typical Characteristics





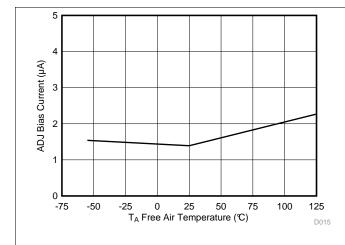
Typical Characteristics (continued)



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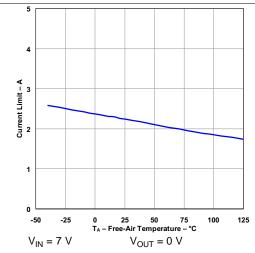
Typical Characteristics (continued)



3.5 Current Limit - A T_A = 25°C T_A = 125°C 0.5 10 12 Input/Output Differential Voltage - V $\Delta V_{OUT} = 100 \text{ mV}$

Figure 13. FB Bias Current vs Temperature

Figure 14. Current Limit vs Input/Output Differential Voltage



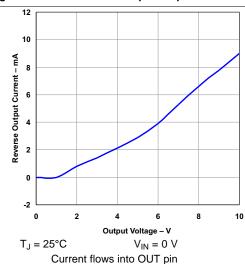
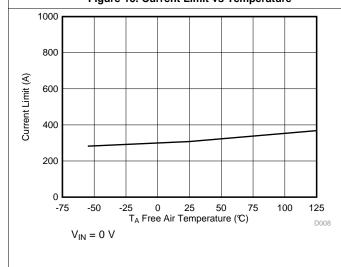


Figure 15. Current Limit vs Temperature

Figure 16. Reverse Output Current vs Output Voltage



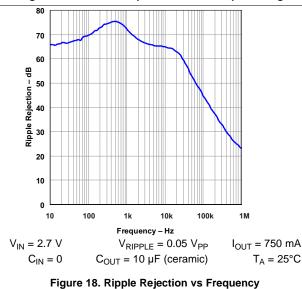
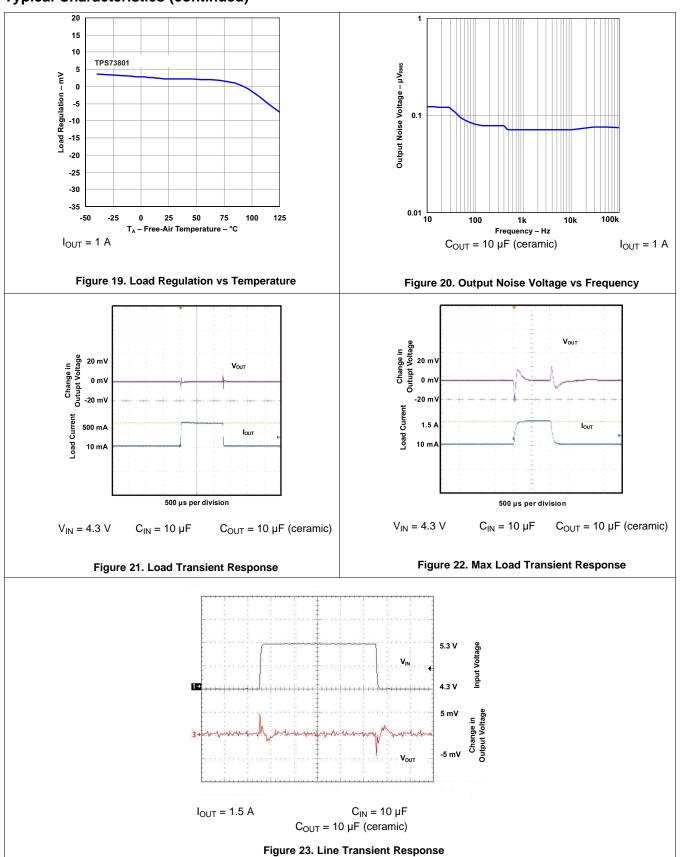


Figure 17. Reverse Output Current vs Temperature



Typical Characteristics (continued)



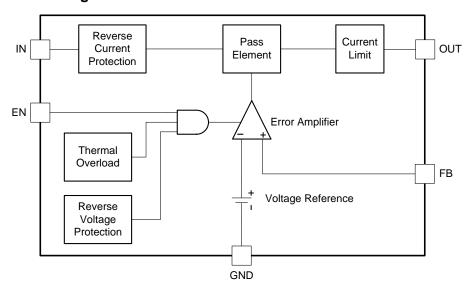
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7 Detailed Description

7.1 Overview

The TPS73801-SEP is a 1-A LDO regulator optimized for fast transient response. The devices are capable of supplying 1 A at a dropout voltage of 300 mV. The low operating quiescent current (1 mA) drops to less than 1 μ A in shutdown. In addition to the low quiescent current, the TPS73801-SEP regulators incorporate several protection features which make them ideal for use in battery-powered systems. The devices are protected against both reverse input and reverse output voltages. In battery-backup applications where the output can be held up by a backup battery when the input is pulled to ground, the TPS73801-SEP acts as if it has a diode in series with its output and prevents reverse current flow. Additionally, in dual-supply applications where the regulator load is returned to a negative supply, the output can be pulled below ground by as much as 20 V and still allow the device to start and operate.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Adjustable Operation

The TPS73801-SEP has an adjustable output voltage range of 1.21 V to 20 V. The output voltage is set by the ratio of two external resistors as shown in Figure 24. The device maintains the voltage at the FB pin at 1.21 V referenced to ground. The current in R1 is then equal to (1.21 V / R1), and the current in R2 is the current in R1 plus the FB pin bias current. The FB pin bias current, 3 μ A at 25°C, flows through R2 into the FB pin. The output voltage can be calculated using the formula shown in Equation 1. The value of R1 should be less than 4.17 μ C to minimize errors in the output voltage caused by the FB pin bias current. Note that in shutdown the output is turned off, and the divider current is zero.

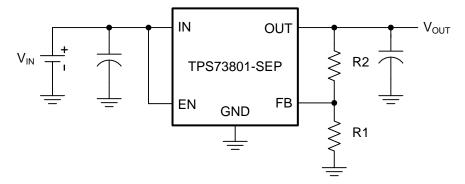


Figure 24. Adjustable Operation

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The output voltage can be set using the following equations:

$$V_{OUT} = 1.21 V(1 + \frac{R^2}{R^1}) + I_{FB} \times R^2$$
 (1)

$$V_{FB} = 1.21 \text{ V}$$
 (2)

$$I_{FB} = 3 \mu A \text{ at } 25^{\circ} C$$
 (3)

7.3.2 Fixed Operation

The TPS73801-SEP can be used in a fixed voltage configuration. By connecting the FB pin to OUT, the TPS73801-SEP will regulate the output to 1.21 V. During fixed voltage operation, the FB pin can be used for a Kelvin connection if routed separately to the load. This allows the regulator to compensate for voltage drop across parasitic resistances (Rp) between the output and the load. This becomes more crucial with higher load currents.

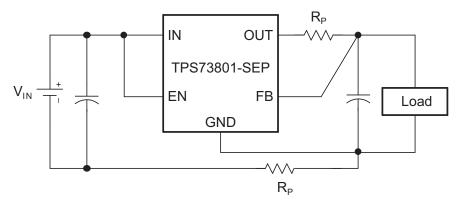


Figure 25. Kelvin Sense Connection

7.3.3 Overload Recovery

Like many IC power regulators, the TPS73801-SEP has safe operating area protection. The safe area protection decreases the current limit as input-to-output voltage increases and keeps the power transistor inside a safe operating region for all values of input-to-output voltage. The protection is designed to provide some output current at all values of input-to-output voltage up to the device breakdown.

When power is first turned on, as the input voltage rises, the output follows the input, allowing the regulator to start up into very heavy loads. During start up, as the input voltage is rising, the input-to-output voltage differential is small, allowing the regulator to supply large output currents. With a high input voltage, a problem can occur wherein removal of an output short does not allow the output voltage to recover. Other regulators also exhibit this phenomenon, so it is not unique to the TPS73801-SEP.

The problem occurs with a heavy output load when the input voltage is high and the output voltage is low. Common situations occur immediately after the removal of a short circuit or when the shutdown pin is pulled high after the input voltage has already been turned on. The load line for such a load may intersect the output current curve at two points. If this happens, there are two stable output operating points for the regulator. With this double intersection, the input power supply may need to be cycled down to zero and brought up again to make the output recover.

7.3.4 Output Voltage Noise

The TPS73801-SEP regulators have been designed to provide low output voltage noise over the 10-Hz to 100kHz bandwidth while operating at full load. Output voltage noise is typically 40 nV/√Hz over this frequency bandwidth for the TPS73801-SEP. For higher output voltages (generated by using a resistor divider), the output voltage noise is gained up accordingly. This results in RMS noise over the 10-Hz to 100-kHz bandwidth of 14 μVRMS for the TPS73801-SEP.

Higher values of output voltage noise may be measured when care is not exercised with regards to circuit layout and testing. Crosstalk from nearby traces can induce unwanted noise onto the output of the TPS73801-SEP. Power supply ripple rejection must also be considered; the TPS73801-SEP regulators do not have unlimited power-supply rejection and pass a small portion of the input noise through to the output.

7.3.5 Protection Features

The TPS73801-SEP regulators incorporate several protection features that make them ideal for use in battery-powered circuits. In addition to the normal protection features associated with monolithic regulators, such as current limiting and thermal limiting, the devices are protected against reverse input voltages, reverse output voltages, and reverse voltages from output to input.

Current limit protection and thermal overload protection are intended to protect the device against current overload conditions at the output of the device. For normal operation, the junction temperature should not exceed 125°C.

The input of the device withstands reverse voltages of 20 V. Current flow into the device is limited to less than 1 mA (typically less than 100 μ A), and no negative voltage appears at the output. The device protects both itself and the load. This provides protection against batteries that can be plugged in backward.

The output of the TPS73801-SEP can be pulled below ground without damaging the device. If the input is left open circuit or grounded, the output can be pulled below ground by 20 V. The output acts like an open circuit; no current flows out of the pin. If the input is powered by a voltage source, the output sources the short-circuit current of the device and protects itself by thermal limiting. In this case, grounding the EN pin turns off the device and stops the output from sourcing the short-circuit current.

The FB pin can be pulled above or below ground by as much as 7 V without damaging the device. If the input is left open circuit or grounded, the FB pin acts like an open circuit when pulled below ground and like a large resistor (typically $5 \text{ k}\Omega$) in series with a diode when pulled above ground.

In situations where the FB pin is connected to a resistor divider that would pull the FB pin above its 7-V clamp voltage if the output is pulled high, the FB pin input current must be limited to less than 5 mA. For example, a resistor divider is used to provide a regulated 1.5-V output from the 1.21-V reference when the output is forced to 20 V. The top resistor of the resistor divider must be chosen to limit the current into the FB pin to less than 5 mA when the FB pin is at 7 V. The 13-V difference between OUT and FB pins divided by the 5-mA maximum current into the FB pin yields a minimum top resistor value of 2.6 k Ω .

In circuits where a backup battery is required, several different input/output conditions can occur. The output voltage may be held up while the input is either pulled to ground, pulled to some intermediate voltage, or is left open circuit. When the IN pin of the TPS73801-SEP is forced below the OUT pin or the OUT pin is pulled above the IN pin, input current typically drops to less than 2 μ A. This can happen if the input of the device is connected to a discharged (low voltage) battery and the output is held up by either a backup battery or a second regulator circuit. The state of the EN pin has no effect on the reverse output current when the output is pulled above the input.

7.4 Device Functional Modes

See the device modes in Table 1.

Table 1. Device Modes

EN	DEVICE STATE
Н	Regulated voltage
L	Shutdown

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8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

8.1.1 Output Capacitance and Transient Response

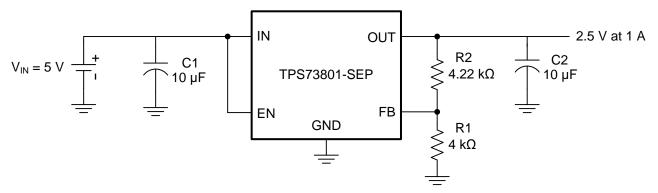
The TPS73801-SEP regulators are designed to be stable with a wide range of output capacitors. The ESR of the output capacitor affects stability, most notably with small capacitors. A minimum output capacitor of 10 μ F with an ESR of 3 Ω or less is recommended to prevent oscillations. Larger values of output capacitance can decrease the peak deviations and provide improved transient response for larger load current changes. Bypass capacitors, used to decouple individual components powered by the TPS73801-SEP, increase the effective output capacitor value.

Extra consideration must be given to the use of ceramic capacitors. Ceramic capacitors are manufactured with a variety of dielectrics, each with different behavior over temperature and applied voltage. The most common dielectrics used are Z5U, Y5V, X5R and X7R. The Z5U and Y5V dielectrics are good for providing high capacitances in a small package, but exhibit strong voltage and temperature coefficients. When used with a 5-V regulator, a 10- μ F Y5V capacitor can exhibit an effective value as low as 1 μ F to 2 μ F over the operating temperature range. The X5R and X7R dielectrics result in more stable characteristics and are more suitable for use as the output capacitor. The X7R type has better stability across temperature, while the X5R is less expensive and is available in higher values.

Voltage and temperature coefficients are not the only sources of problems. Some ceramic capacitors have a piezoelectric response. A piezoelectric device generates voltage across its terminals due to mechanical stress, similar to the way a piezoelectric accelerometer or microphone works. For a ceramic capacitor, the stress can be induced by vibrations in the system or thermal transients.

8.2 Typical Application

This section will highlight some of the design considerations when implementing this device in various applications.



NOTE: All capacitors are ceramic.

Figure 26. Adjustable Output Voltage Operation

TEXAS INSTRUMENTS

Typical Application (continued)

8.2.1 Design Requirements

Table 2 shows the design parameters for this application.

Table 2. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage (V _{IN})	5 V
Output voltage (V _{OUT})	2.5 V
Output current (I _{OUT})	0 to 1 A
Load regulation	1%

8.2.2 Detailed Design Procedure

The TPS73801-SEP has an adjustable output voltage range of 1.21 to 20 V. The output voltage is set by the ratio of two external resistors R1 and R2 as shown in Figure 26. The device maintains the voltage at the FB pin at 1.21 V referenced to ground. The current in R1 is then equal to (1.21 V / R1), and the current in R2 is the current in R1 plus the FB pin bias current. The FB pin bias current, 3 μ A at 25°C, flows through R2 into the FB pin. The output voltage can be calculated using Equation 5.

$$V_{OUT} = 1.21 V(1 + \frac{R2}{R1}) + I_{FB} \times R2$$
 (5)

The value of R1 should be less than 4.17 k Ω to minimize errors in the output voltage caused by the FB pin bias current. Note that in shutdown the output is turned off, and the divider current is zero. For an output voltage of 2.50 V, R1 will be set to 4.0 k Ω . R2 is then found to be 4.22 k Ω using the equation above.

$$V_{\text{OUT}} = 1.21V(1 + \frac{4.22k\Omega}{4.0k\Omega}) + 3\mu A \times 4.22k\Omega$$
 (6)

$$V_{OLIT} = 2.50 \text{ V}$$
 (7)

The adjustable device is tested and specified with the FB pin tied to the OUT pin for an output voltage of 1.21 V. Specifications for output voltages greater than 1.21 V are proportional to the ratio of the desired output voltage to 1.21 V: V_{OUT} / 1.21 V. For example, load regulation for an output current change of 1 mA to 1.5 A is –2 mV (typ) at V_{OUT} = 1.21 V. At V_{OUT} = 2.50 V, the typical load regulation is:

$$(2.50 \text{ V} / 1.21 \text{ V})(-2 \text{ mV}) = -4.13 \text{ mV}$$
 (8)

Figure 27 shows the actual change in output is about 3 mV for a 1-A load step. The maximum load regulation at 25° C is -8 mV. At $V_{OUT} = 2.50$ V, the maximum load regulation is:

$$(2.50 \text{ V} / 1.21 \text{ V})(-8 \text{ mV}) = -16.53 \text{ mV}$$
 (9)

Since 16.53 mV is only 0.7% of the 2.5 V output voltage, the load regulation will meet the design requirements.

8.2.3 Application Curve

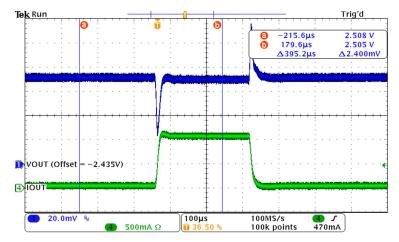


Figure 27. 1-A Load Transient Response

9 Power Supply Recommendations

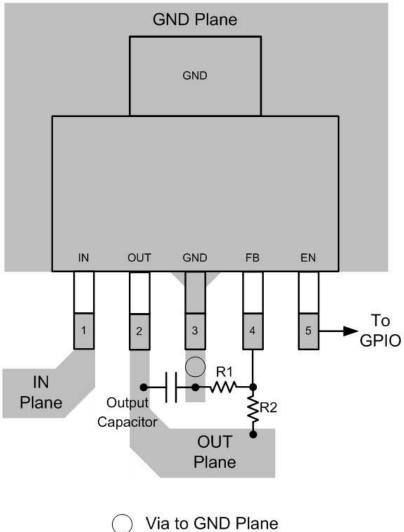
The device is designed to operate with an input voltage supply up to 20 V. The minimum input voltage should provide adequate headroom greater than the dropout voltage in order for the device to have a regulated output. If the input supply is noisy, additional input capacitors with low ESR can help improve the output noise performance.

10 Layout

10.1 Layout Guidelines

- 1. For best performance, all traces should be as short as possible.
- 2. Use wide traces for IN, OUT, and GND to minimize the parasitic electrical effects.
- 3. A minimum output capacitor of 10 μF with an ESR of 3 Ω or less is recommended to prevent oscillations. X5R and X7R dielectrics are preferred.
- 4. Place the Output Capacitor as close as possible to the OUT pin of the device.
- 5. The tab of the DCQ package should be connected to ground.

10.2 Layout Example



O VIA to GND I larie

Figure 28. SOT-223 Layout Example (DCQ)

10.3 Thermal Considerations

The power handling capability of the device is limited by the recommended maximum operating junction temperature (125°C). The power dissipated by the device is made up of two components:

- 1. Output current multiplied by the input/output voltage differential: $I_{OUT}(V_{IN} V_{OUT})$
- 2. GND pin current multiplied by the input voltage: $I_{GND} \times V_{IN}$

The GND pin current can be found using the GND Pin Current graphs in *Typical Characteristics* section. Power dissipation is equal to the sum of the two components listed above.

The TPS73801-SEP series regulators have internal thermal limiting designed to protect the device during overload conditions. For continuous normal conditions, the recommended maximum operating junction temperature is 125°C. It is important to give careful consideration to all sources of thermal resistance from junction to ambient. Additional heat sources mounted nearby must also be considered.

10.3.1 Calculating Junction Temperature

Example: Given an output voltage of 3.3 V, an input voltage range of 4 V to 6 V, an output current range of 0 mA to 500 mA, and a maximum ambient temperature of 50°C, what is the operating junction temperature?

The power dissipated by the device is equal to:

$$I_{OUT(MAX)}(V_{IN(MAX)} - V_{OUT}) + I_{GND}(V_{IN(MAX)})$$

where

- I_{OUT(MAX)} = 500 mA
- $V_{IN(MAX)} = 6 \text{ V}$

$$I_{GND}$$
 at $(I_{OUT} = 500 \text{ mA}, V_{IN} = 6 \text{ V}) = 10 \text{ mA}$ (10)

So,

$$P = 500 \text{ mA} \times (6 \text{ V} - 3.3 \text{ V}) + 10 \text{ mA} \times 6 \text{ V} = 1.41 \text{ W}$$
 (11)

The thermal resistance of the DCQ package is 50.5°C/W. So the junction temperature rise above ambient is approximately equal to:

$$1.41 \text{ W} \times 50.5^{\circ}\text{C/W} = 71.2^{\circ}\text{C}$$
 (12)

The junction temperature rise can then be added to the maximum ambient temperature to find the operating junction temperature (T_J) :

$$T_{J} = 50^{\circ}\text{C} + 71.2^{\circ}\text{C} = 121.2^{\circ}\text{C}$$
 (13)

TEXAS INSTRUMENTS

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11.5 术语表

SLYZ022 — TI 术语表。

这份术语表列出并解释术语、缩写和定义。



12 机械、封装和可订购信息

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PACKAGING INFORMATION

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
TPS73801MDCQPSEP	ACTIVE	SOT-223	DCQ	6	78	RoHS & Green	NIPDAUAG	Level-2-260C-1 YEAR	-55 to 125	73801-SP	Samples
TPS73801MDCQTPSEP	ACTIVE	SOT-223	DCQ	6	250	RoHS & Green	NIPDAUAG	Level-2-260C-1 YEAR	-55 to 125	73801-SP	Samples
V62/18616-01XE	ACTIVE	SOT-223	DCQ	6	250	RoHS & Green	NIPDAUAG	Level-2-260C-1 YEAR	-55 to 125	73801-SP	Samples
V62/18616-01XE-T	ACTIVE	SOT-223	DCQ	6	78	RoHS & Green	NIPDAUAG	Level-2-260C-1 YEAR	-55 to 125	73801-SP	Samples

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- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
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	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

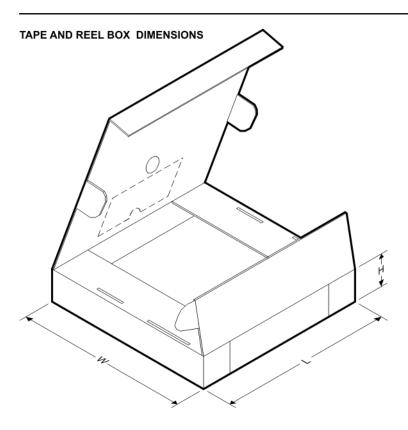
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS73801MDCQTPSEP	SOT-223	DCQ	6	250	177.8	12.4	7.1	7.45	1.88	8.0	12.0	Q3

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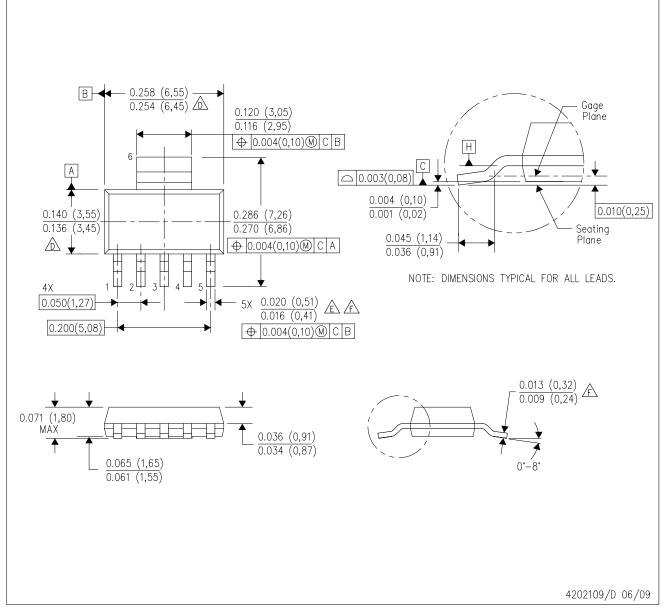


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
TPS73801MDCQTPSEP	SOT-223	DCQ	6	250	213.0	191.0	35.0	

DCQ (R-PDSO-G6)

PLASTIC SMALL-OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Controlling dimension in inches.
- Body length and width dimensions are determined at the outermost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs, and interlead flash, but including any mismatch between the top and the bottom of the plastic body.
- Lead width dimension does not include dambar protrusion.
- Lead width and thickness dimensions apply to solder plated leads.
- G. Interlead flash allow 0.008 inch max.
- H. Gate burr/protrusion max. 0.006 inch.
- I. Datums A and B are to be determined at Datum H.



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